



UNIVERSITY OF TEHRAN

Report Computer Assignment 1

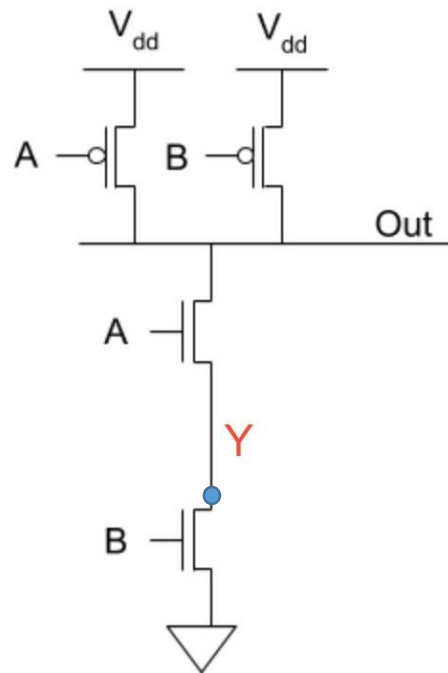
Digital Logic Design, ECE 367 / Digital Systems I, ECE 894

Danial Saeedi

Problem 1

Circuit Diagram

Here's the circuit that I'm analyzing:



NAND CMOS Circuit

Verilog Code

Here's my Verilog Code for Switch Level NAND Gate. (I used sublime for coloring this code).

The y wire is shown in the Circuit Diagram. a and b are the input of NAND Gate and the output is w :

```
1 `timescale 1ns/1ns
2 module MyNAND (input a,b,output w);
3     wire y;
4     supply1 Vdd;
5     supply0 Gnd;
6     pmos #(5,6,7) T1(w,Vdd,a);
7     pmos #(5,6,7) T2(w,Vdd,b);
8     nmos #(3,4,5) T3(y,Gnd,b);
9     nmos #(3,4,5) T4(w,y,a);
10 endmodule
```

Worst-case Delay

To 1 : It takes 5ns to change the output of the PMOS transistors to 1. It takes $5 + 5 = 10\text{ns}$ to get Hi-Z from pull-down structure. Thus it takes **10ns** in the worst case to change the output of the NAND Gate to 1.

To 1 = 10ns

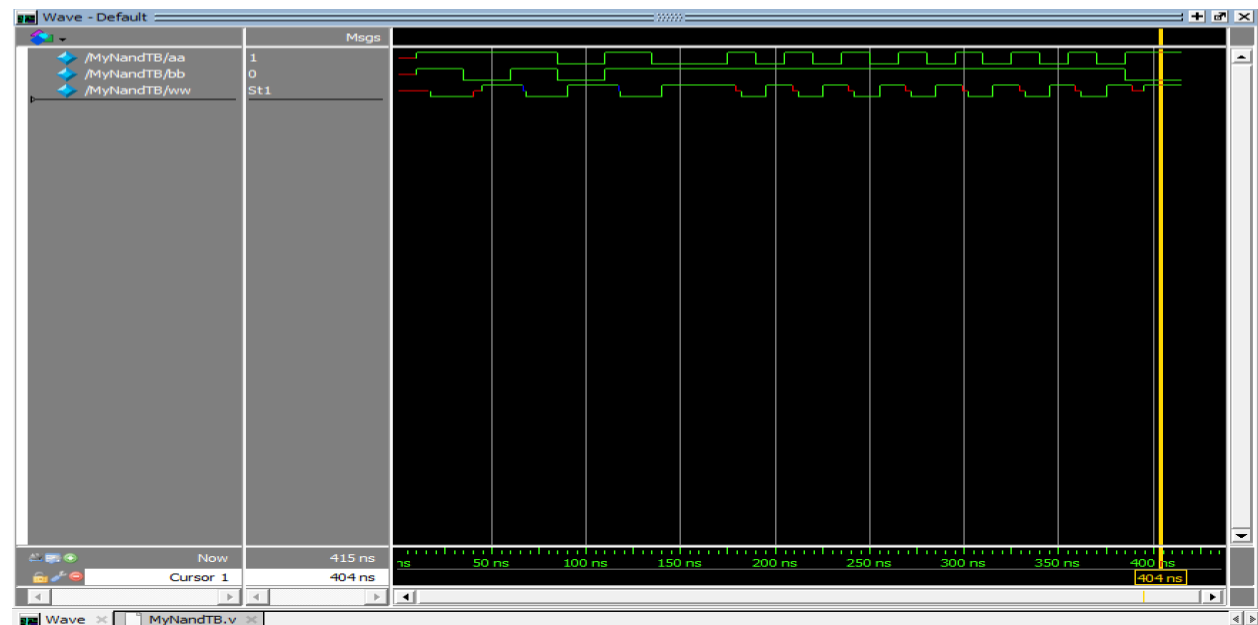
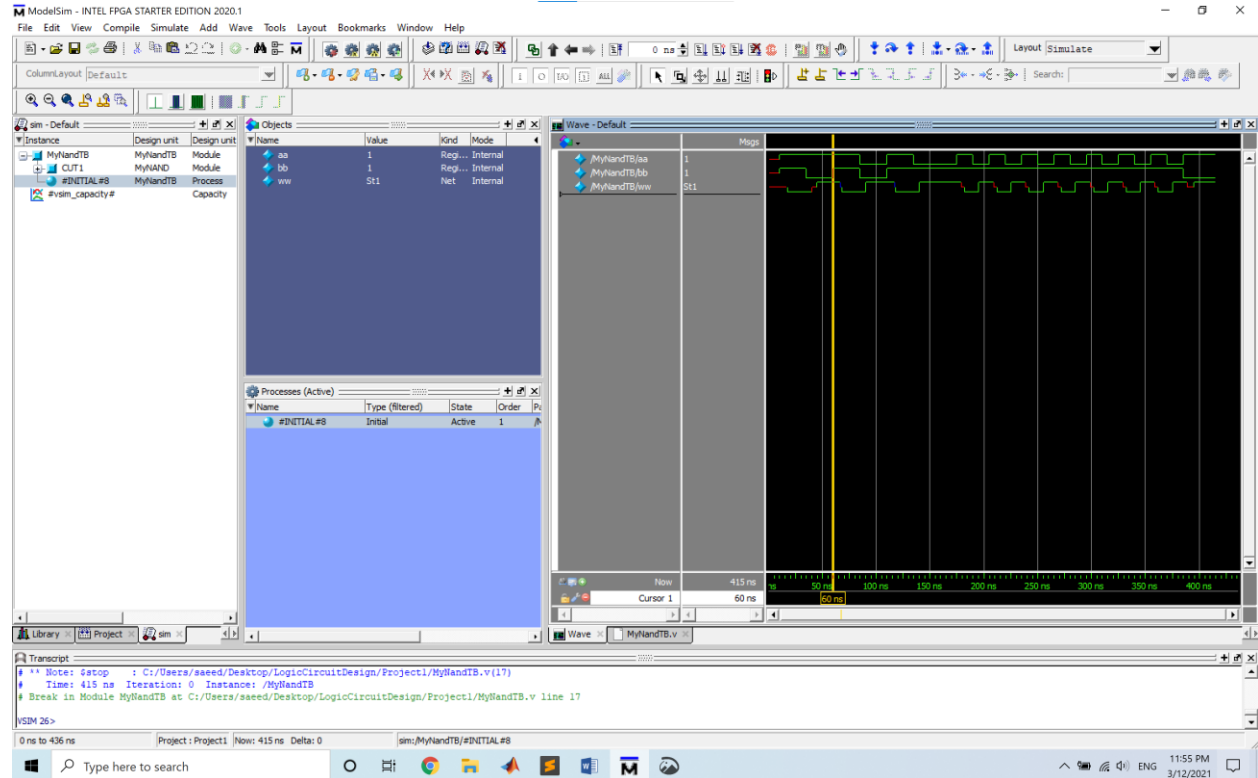
To 0 : It takes 7ns to change the output of pull-up structure to Hi-Z. It takes $4 + 4 = 8\text{ns}$ to change the output of pull-down structure to 0

To 0 = 8ns

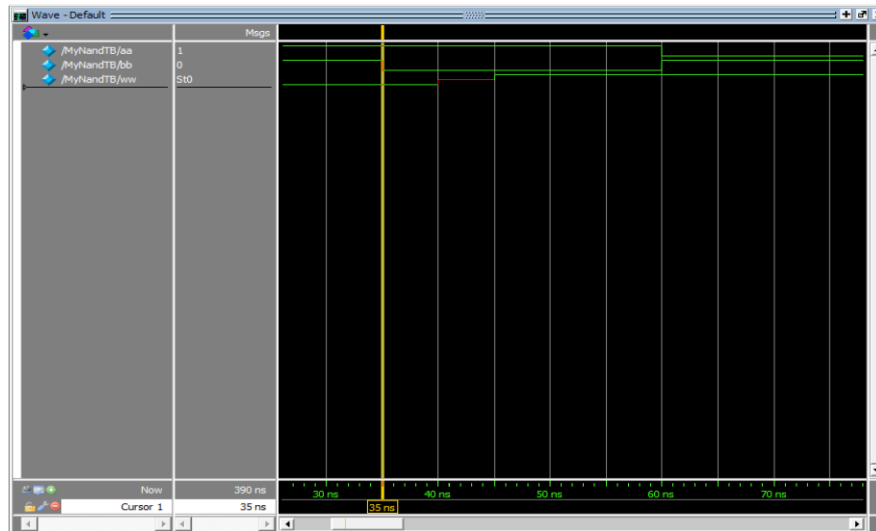
Testbench

```
1 `timescale 1ns/1ns
2 module MyNandTB();
3     //Inputs
4     reg aa,bb;
5     //The NAND output
6     wire ww;
7     MyNAND CUT1(aa,bb,ww);
8     initial begin
9         #10 aa = 1;bb = 1;
10        #25 aa = 1;bb = 0;
11        #25 aa = 1;bb = 1;
12        #25 aa = 0;bb = 0;
13        #25 aa = 1;bb = 1;
14        #25 aa = 0;bb = 1;
15        #25
16        repeat(15) #15 aa = ~aa; bb = ~bb;
17        #30 $stop;
18    end
19 endmodule
```

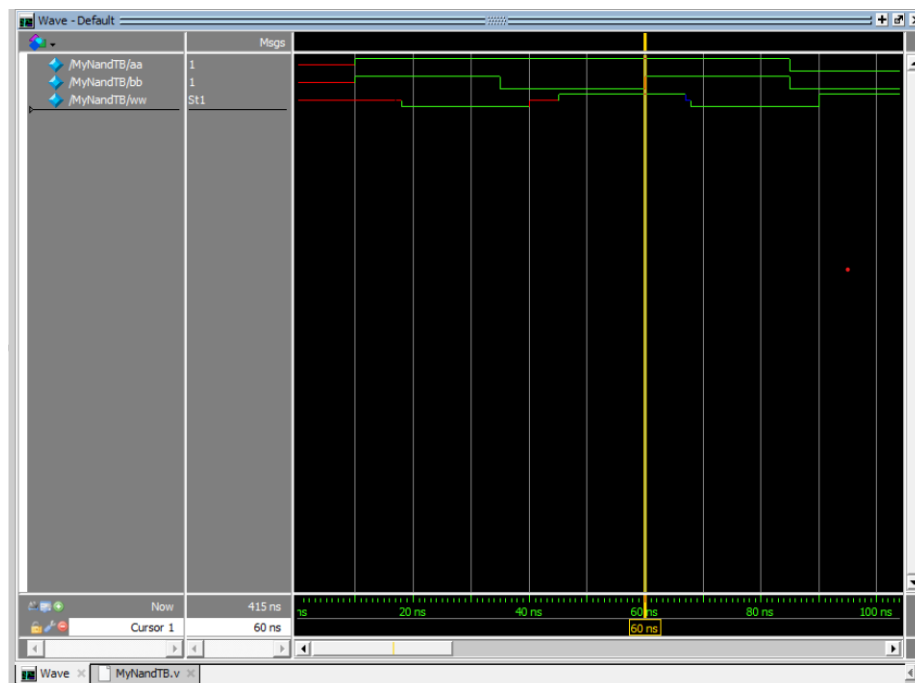
Simulation Result



The To1 worst case happens when the input changes from $a = 1$ and $b = 1$ to $a = 1$ and $b = 0$. We expect to see 10ns delay. We can see from the zoomed waveform, To1 delay is correct: (The output changes to 1 at 45ns)



The To0 worst-case delay happens when the inputs changes from $a = 1$ and $b = 0$ to $a = 1$ and $b = 1$. As we expect, the To0 delay is 8ns:



Here's the circuit that I'm analyzing:

Testbench

```
1 `timescale 1ns/1ns
2 module MyTriStateTB();
3     wire yy;
4     reg aa,enable;
5     MyTriStateBuffer CUT1(aa,enable,yy);
6     initial begin
7         #10 aa = 1;enable = 0;
8         #21 aa = 0;enable = 1;
9         #21 aa = 1;enable = 1;
10        #21 aa = 0;enable = 0;
11        #21 aa = 1;enable = 1;
12        #20
13        repeat(15) #15 aa = ~aa; enable = ~enable;
14        #30 $stop;
15    end
16 endmodule
```

Worst-case Delay

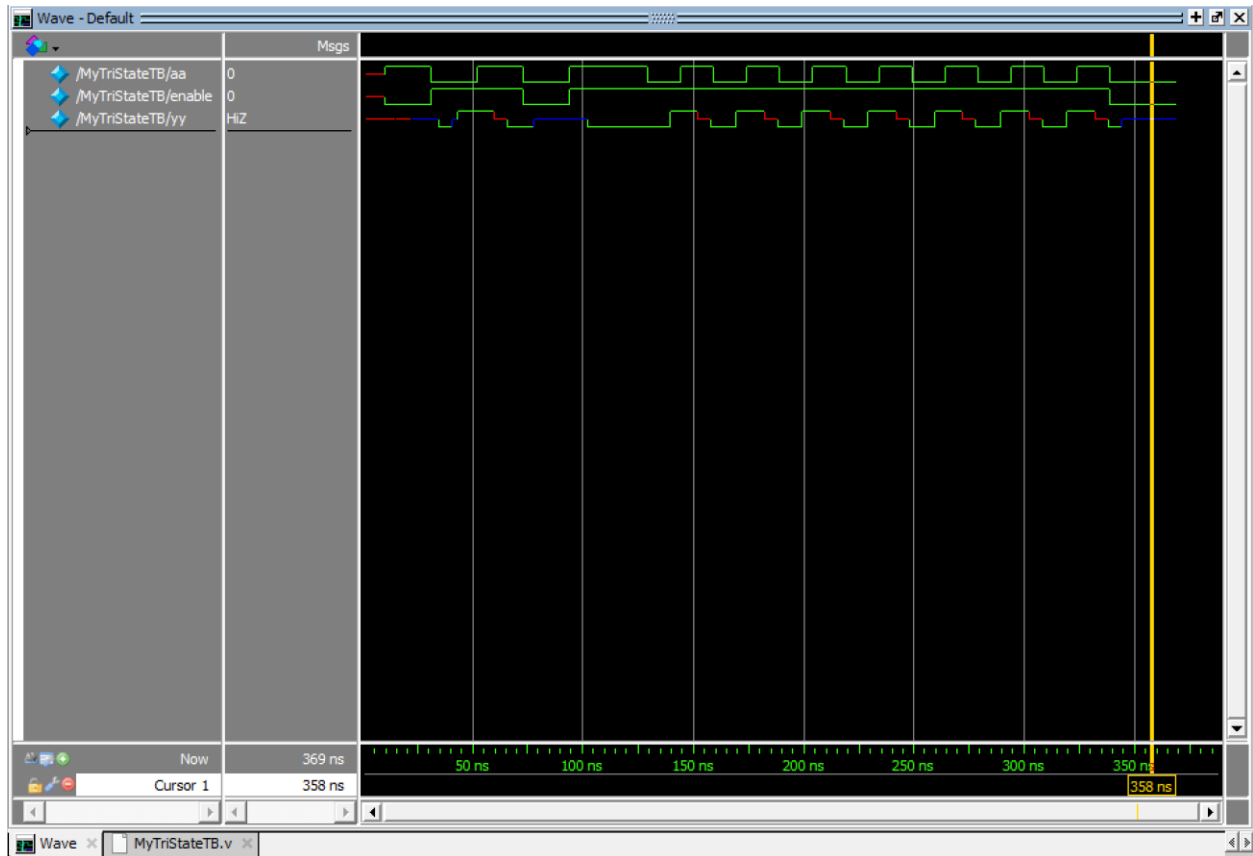
To 1 : It takes $6 + 5 = 11\text{ns}$ to changes the output of the pull-up structure to 1.(NOT gate delay is included)

To 1 = 11ns

To 0 : It takes $7 + 7 = 14\text{ns}$ to changes the output of the pull-up structure to Hi-Z. And it takes $4 + 4 = 8\text{ns}$ to to changes the output of the pull-down structure to 0.

To 0 = 14ns

Simulation Result

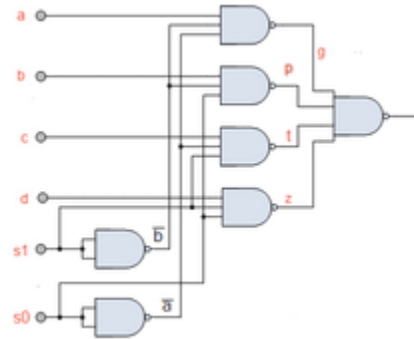


As expected, the To 1 and To 0 are 11ns and 14ns respectively.

Problem 3

Circuit Diagram

Here's the circuit that I'm analyzing:



Approach 1

From part 1, we know that NAND gate delays are #(10,8). We use NAND from VerilogSystem for this approach.

Verilog Code For Approach 1

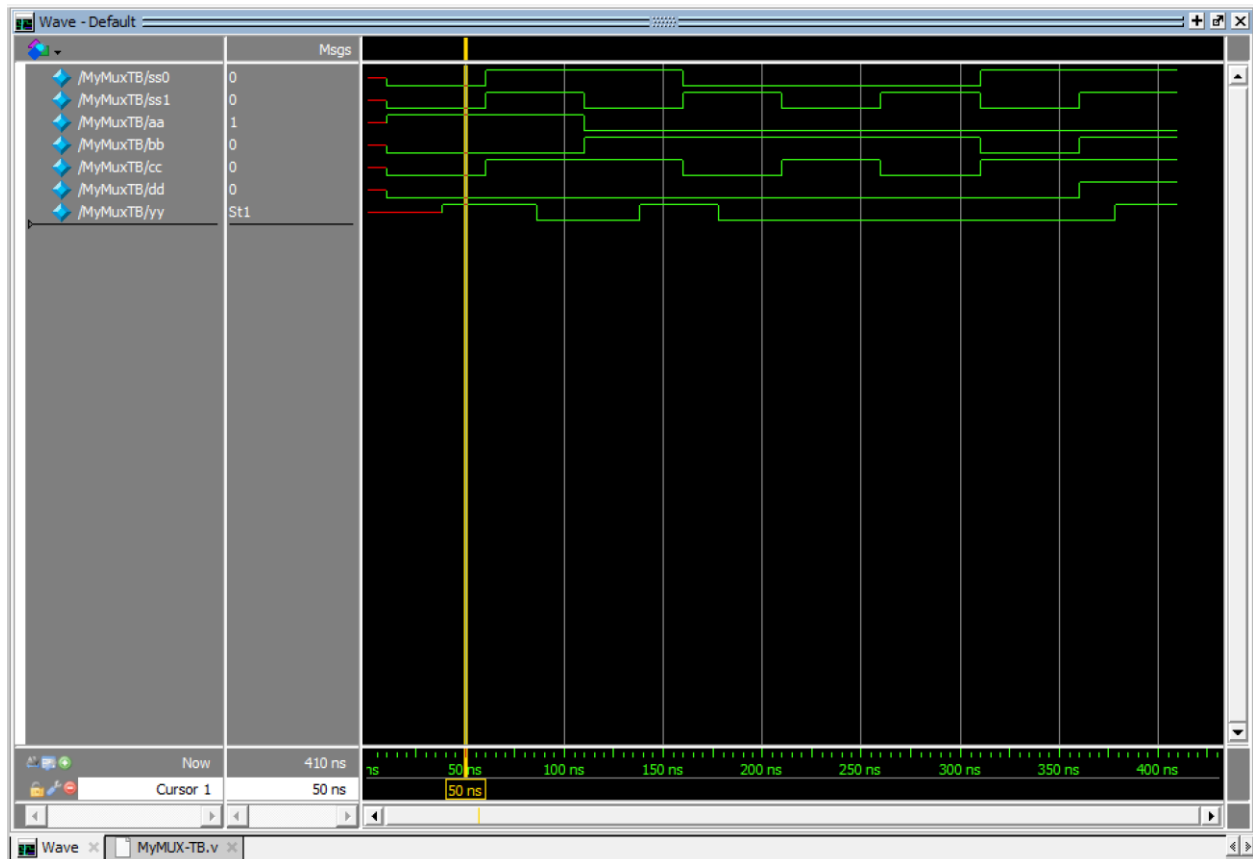
The s0_not,s1_not, g,p,t and z wires are shown in the circuit diagram.

```
1 `timescale 1ns/1ns
2 module MyMUX(
3     input s0,s1,a,b,c,d,
4     output y
5 );
6     wire s0_not,s1_not,g,p,t,z;
7     nand #(10,8) nand_1(s0_not,s0,s0);
8     nand #(10,8) nand_2(s1_not,s1,s1);
9     nand #(10,8) nand_3(g,a,s1_not,s0_not);
10    nand #(10,8) nand_4(p,b,s1_not,s0);
11    nand #(10,8) nand_5(t,c,s1,s0_not);
12    nand #(10,8) nand_6(z,d,s1,s0);
13    nand #(10,8) nand_7(y,g,p,t,z);
14 endmodule
```

Testbench For Approach 1

```
1 `timescale 1ns/1ns
2 module MyMuxTB();
3     wire yy;
4     reg ss0,ss1,aa,bb,cc,dd;
5     MyMUX CUT1(ss0,ss1,aa,bb,cc,dd,yy);
6     initial begin
7         #10 ss1 = 0; ss0 = 0; aa = 1;bb = 0; cc = 0;dd = 0;
8         #50 ss1 = 1; ss0 = 1; aa = 1;bb = 0; cc = 1;dd = 0;
9         #50 ss1 = 0; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 0;
10        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
11        #50 ss1 = 0; ss0 = 0; aa = 0;bb = 1; cc = 1;dd = 0;
12        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
13        #50 ss1 = 0; ss0 = 1; aa = 0;bb = 0; cc = 1;dd = 0;
14        #50 ss1 = 1; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 1;
15        #50 $stop;
16    end
17 endmodule
18
```

Simulation Result For Approach 1



Analyzing Simulation Result

The output of MUX 4 to 1 is the result we expect.

For instance when the inputs are :

ss1 = 0; ss0 = 0; aa = 1;bb = 0; cc = 0;dd = 0;

We expect the output be 1. After 28ns delay, the output changes to 1.

Approach 2

We use the NAND gate module from part 1. I've created three NAND gates with 2, 3 and 4 inputs.

Note that this approach is much more accurate than approach 1. Because we're simulating in transistor level.

Verilog Code for 3 and 4 inputs NAND gate :

Three Inputs NAND Gate

```
1 `timescale 1ns/1ns
2 module ThreeInputsNand(input a,b,c,output w);
3     wire g,z;
4     supply1 Vdd;
5     supply0 Gnd;
6     pmos #(5,6,7) T1(w,Vdd,a);
7     pmos #(5,6,7) T2(w,Vdd,b);
8     pmos #(5,6,7) T3(w,Vdd,c);
9     nmos #(3,4,5) T4(w,z,a);
10    nmos #(3,4,5) T5(z,g,b);
11    nmos #(3,4,5) T6(g,Gnd,c);
12 endmodule
```

Four Inputs NAND Gate

```
1 `timescale 1ns/1ns
2 module ThreeInputsNand(input a,b,c,d,output w);
3     wire g,p,z;
4     supply1 Vdd;
5     supply0 Gnd;
6     pmos #(5,6,7) T1(w,Vdd,a);
7     pmos #(5,6,7) T2(w,Vdd,b);
8     pmos #(5,6,7) T3(w,Vdd,c);
9     pmos #(5,6,7) T4(w,Vdd,d);
10    nmos #(3,4,5) T5(w,z,a);
11    nmos #(3,4,5) T6(z,g,b);
12    nmos #(3,4,5) T7(g,p,c);
13    nmos #(3,4,5) T8(p,Gnd,d);
14 endmodule
```

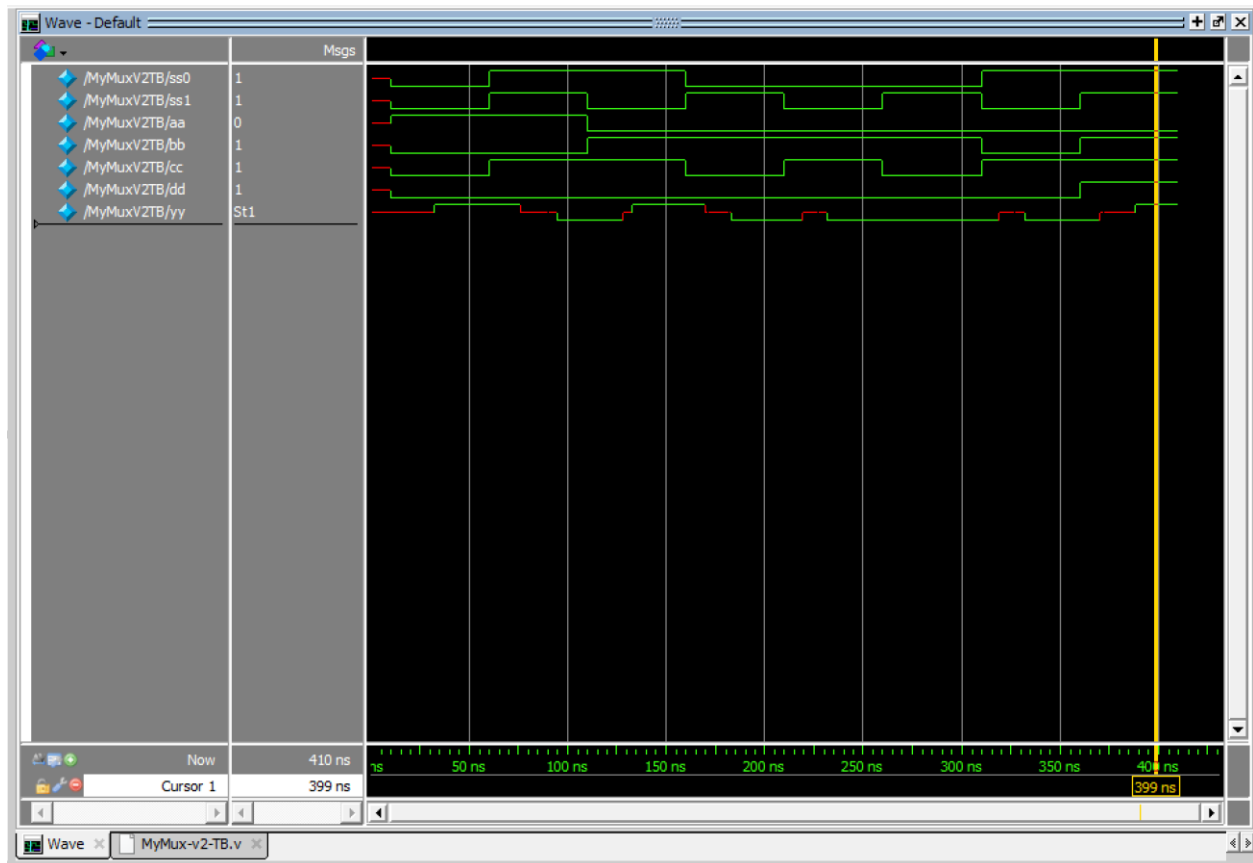
Verilog Code For Approach 2

```
1 `timescale 1ns/1ns
2 module MyMuxV2(
3     input s0,s1,a,b,c,d,
4     output y
5 );
6     wire s0_not,s1_not,g,p,t,z;
7     MyNAND nand_1(s0,s0,s0_not);
8     MyNAND nand_2(s1,s1,s1_not);
9     ThreeInputsNand nand_3(a,s1_not,s0_not,g);
10    ThreeInputsNand nand_4(b,s1_not,s0,p);
11    ThreeInputsNand nand_5(c,s1,s0_not,t);
12    ThreeInputsNand nand_6(d,s1,s0,z);
13    FourInputsNand nand_7(g,p,t,z,y);
14 endmodule
```

Testbench For Approach 2

```
1 `timescale 1ns/1ns
2 module MyMuxV2TB();
3     wire yy;
4     reg ss0,ss1,aa,bb,cc,dd;
5     MyMuxV2 CUT1(ss0,ss1,aa,bb,cc,dd,yy);
6     initial begin
7         #10 ss1 = 0; ss0 = 0; aa = 1;bb = 0; cc = 0;dd = 0;
8         #50 ss1 = 1; ss0 = 1; aa = 1;bb = 0; cc = 1;dd = 0;
9         #50 ss1 = 0; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 0;
10        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
11        #50 ss1 = 0; ss0 = 0; aa = 0;bb = 1; cc = 1;dd = 0;
12        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
13        #50 ss1 = 0; ss0 = 1; aa = 0;bb = 0; cc = 1;dd = 0;
14        #50 ss1 = 1; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 1;
15        #50 $stop;
16    end
17 endmodule
```

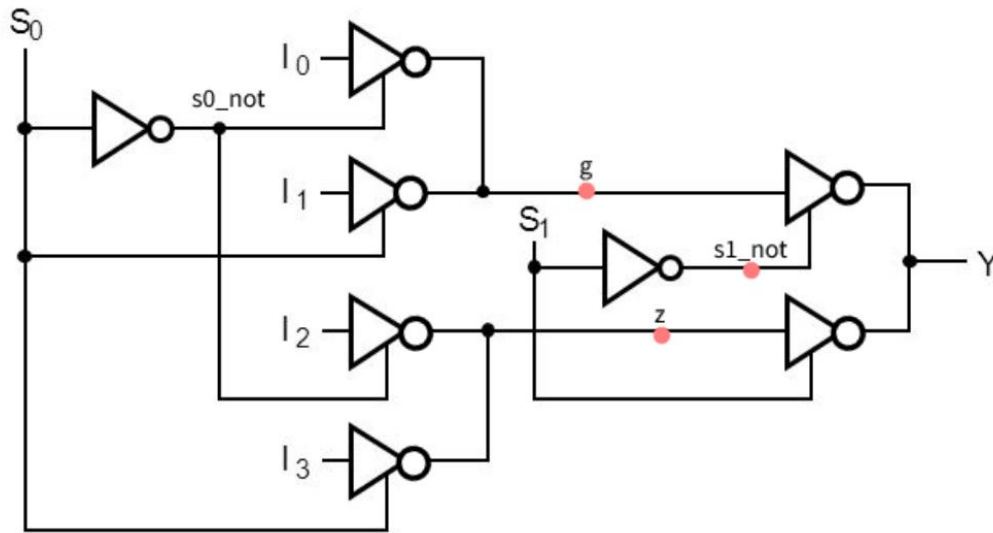
Simulation Result For Approach 2



Problem 4

Circuit Diagram

Here's the circuit that I'm analyzing:



Verilog Code

The s_{0_not} , s_{1_not} , g and z wires are shown in the circuit diagram. I used MyInverter module for the NOT gate and MyTriStateBuffer for the tri-state buffer gate.

```
1  `timescale 1ns/1ns
2  module MyMUX2(
3      input s0,s1,a,b,c,d,
4      output y
5  );
6      wire s0_not,s1_not,g,z;
7      MyInverter inverter_gate1(s0,s0_not);
8      MyInverter inverter_gate2(s1,s1_not);
9
10     MyTriStateBuffer not_buffer1(a,s0_not,g);
11     MyTriStateBuffer not_buffer2(b,s0,g);
12     MyTriStateBuffer not_buffer3(c,s0_not,z);
13     MyTriStateBuffer not_buffer4(d,s0,z);
14
15     MyTriStateBuffer not_buffer5(g,s1_not,y);
16     MyTriStateBuffer not_buffer6(z,s1,y);
17 endmodule
```

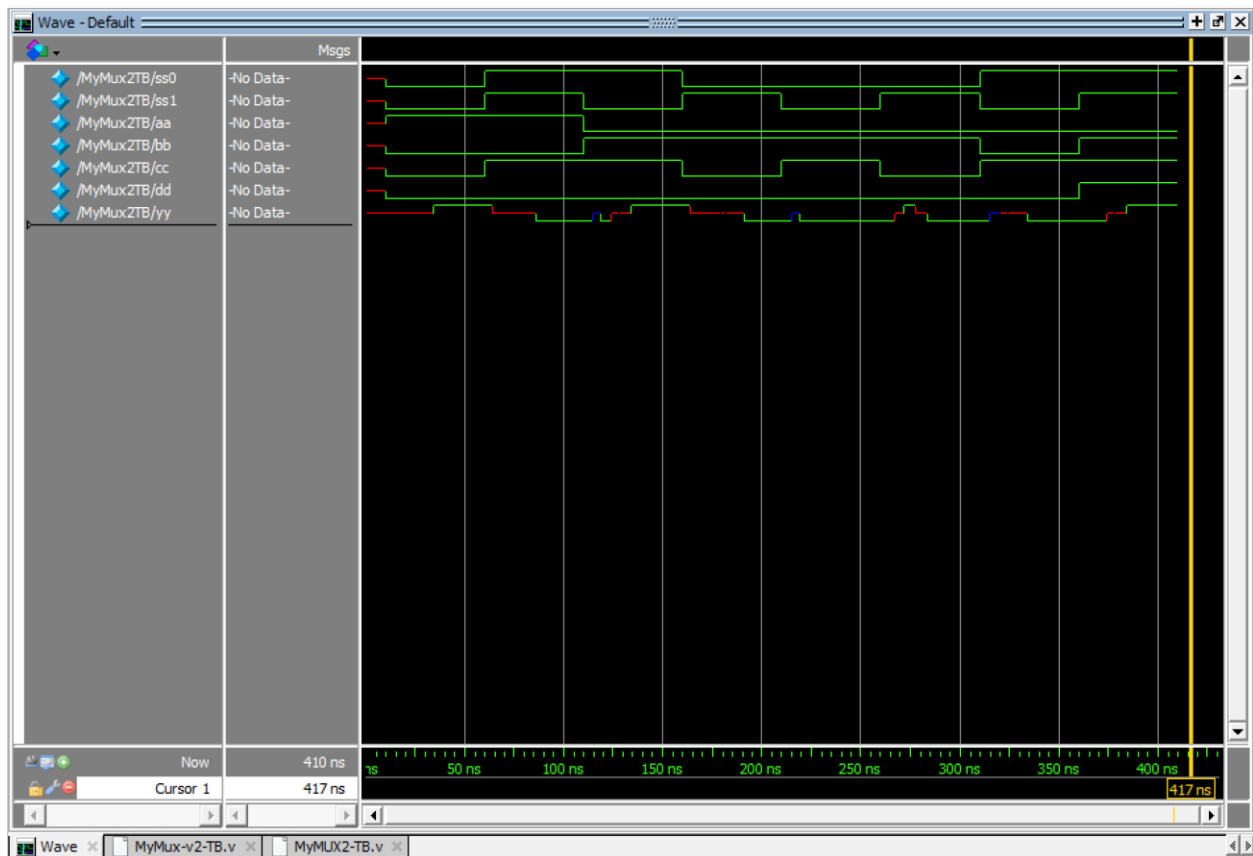
Testbench

```

1  timescale 1ns/1ns
2  module MyMux2TB();
3      wire yy;
4      reg ss0,ss1,aa,bb,cc,dd;
5      MyMUX2 CUT1(ss0,ss1,aa,bb,cc,dd,yy);
6      initial begin
7          #10 ss1 = 0; ss0 = 0; aa = 1;bb = 0; cc = 0;dd = 0;
8          #50 ss1 = 1; ss0 = 1; aa = 1;bb = 0; cc = 1;dd = 0;
9          #50 ss1 = 0; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 0;
10         #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
11         #50 ss1 = 0; ss0 = 0; aa = 0;bb = 1; cc = 1;dd = 0;
12         #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
13         #50 ss1 = 0; ss0 = 1; aa = 0;bb = 0; cc = 1;dd = 0;
14         #50 ss1 = 1; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 1;
15         #50 $stop;
16     end
17 endmodule

```

Simulation Result



Problem 5

Testbench

```
1 `timescale 1ns/1ns
2 module MUXComparison();
3     wire mux1_output,mux2_output;
4     reg ss0,ss1,aa,bb,cc,dd;
5     //Mux Problem 3
6     MyMuxV2 mux1(ss0,ss1,aa,bb,cc,dd,mux1_output);
7     //Mux Problem 4
8     MyMUX2 mux2(ss0,ss1,aa,bb,cc,dd,mux2_output);
9     initial begin
10        #10 ss1 = 0; ss0 = 0; aa = 1;bb = 0; cc = 0;dd = 0;
11        #50 ss1 = 1; ss0 = 1; aa = 1;bb = 0; cc = 1;dd = 0;
12        #50 ss1 = 0; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 0;
13        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
14        #50 ss1 = 0; ss0 = 0; aa = 0;bb = 1; cc = 1;dd = 0;
15        #50 ss1 = 1; ss0 = 0; aa = 0;bb = 1; cc = 0;dd = 0;
16        #50 ss1 = 0; ss0 = 1; aa = 0;bb = 0; cc = 1;dd = 0;
17        #50 ss1 = 1; ss0 = 1; aa = 0;bb = 1; cc = 1;dd = 1;
18        #50 $stop;
19    end
20 endmodule
```

Simulation Result



Calculating the number of transistors from problem 3

Every two-input NAND gate needs 2 PMOS and 2 NMOS transistors.(Total : 4)

Every three-input NAND gate needs 3 PMOS and 3 NMOS transistors.(Total : 6)

Every four-input NAND gate needs 4 PMOS and 4 NMOS transistors.(Total : 8)

There are 2 two-inputs NAND gate and 4 three-inputs NAND gate and 1 four-inputs NAND gate. Thus the total transistors we need for this problem is :

$$2*4+4*6+1*8 = 40 \text{ transistors}$$

Calculating the number of transistors from problem 4

Every NOT gate needs 1 PMOS and 1 NMOS transistors.(Total : 2)

Every tri-state buffer gate needs 6 transistors.

There are 2 NOT gate and 6 tri-state buffer gate. Thus the total transistors we need for this problem is :

$$6*6+2*2 = 40 \text{ transistors}$$

Cost And Power Consumption

Both problems need 40 transistors. So the cost is the same. But problem 3 and 4 need 7 and 8 gates respectively. Each gate is connected to supply 1 and supply 0 in its CMOS structure.

So problem 4 consumes more power than problem 3.